Measuring MOSFET characteristics

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Introduction

These examples demonstrate how to use the Model 2657A High Power System SourceMeter® instrument to measure drain-to-source breakdown and leakage current of a MOSFET.

There are two examples in this section. The first example performs the BV_{dss} measurement, in which a specific current is forced from the drain to the source terminals (I_d) and a voltage measurement is performed (V_{ds}).

The second example performs the I_{dss} measurement in which the Model 2657A sweeps the drain voltage (V_{ds}) and makes drain-current measurements with the FET in the off-state.

In both examples, a second System SourceMeter Instrument is used to apply a voltage from gate to source (V_{qs}). For n-channel, enhancement mode devices, V_{qs} is usually 0 V.

Equipment required

Equipment required:

- One Model 2657A High Power System SourceMeter[®] instrument
- One Series 2600A System SourceMeter Instrument (Model 2611A, Model 2612A, Model 2635A, or Model 2636A)
 - If needed, cables to connect the Series 2600A SourceMeter Instrument to the protection module
 - If needed, cables to connect the protection module to the test fixture
 - If a Model 2611A or Model 2612A is being used, one Model 2600-TRIAX adapter
- If you are not using a Model 8010 High Power Device Test Fixture, you need a Model 2657A-PM-200 Protection Module to ensure that the lower voltage Series 2600A SourceMeter Instrument is protected if the device under test fails
- One GPIB or Ethernet cable to connect the Model 2657A to a computer
- One high voltage MOSFET device enclosed in a safe test fixture, such as the Keithley Instruments Model 8010
- Appropriate cabling to connect the Model 2657A the test fixture

Set up communication

The communication setup is illustrated in the following diagram. This application can be run using any of the supported communication interfaces for the instruments.

For additional detail about remote communications, see "Communications interfaces" in the Model 2657A Reference Manual.

Remote interface connection

Remote interface connection

TSP- Link

TSP- Link

Figure 34: Remote interface and TSP-Link communications setup

Model 2611A, Model 2612A, Model 2635A, or Model 2636A (TSP-Link Node #2)

Item	Description	Qty	Notes
1	IEEE-488 connection	1	GPIB. Model 2657A is IEEE Std 488.1 compliant.
2	CA-180-3A LAN connection	1	Model 2657A is LXI version 1.4 Core 2011 compliant. It supports TCP/IP and complies with IEEE Std 802.3 (ethernet). 10 or 100 Mbps.
3	RS-232 connection	1	

To set the TSP-Link node number using the front-panel interface:

- 1. Press the **MENU** key.
- 2. Select TSPLink.
- 3. Select NODE.
- 4. Use the navigation wheel \odot to adjust the node number.
- 5. Press the **ENTER** key to save the TSP-Link node number.

On the Model 2657A SMU #1 (TSP-Link node #1), perform a TSP-Link reset to update it with the linked instruments:

- 1. Press the **MENU** key.
- 2. Select TSPLink.
- 3. Select **RESET**.

NOTE

If error 1205 is generated during the TSP-link reset, ensure that the Series Model 2657A has a unique TSP-Link node number.

Quick Tip

You can also perform a TSP-Link reset from the remote command interface by sending tsplink.reset() to the Model 2657A. This method is used in the example program.

Device connections

Refer to the following figure to connect the MOSFET in a safe test fixture.

See <u>Safe configuration and test setup</u> (on page 2-1) for information on safely connecting the Model 2657A to a device under test (DUT).

CAUTION

If a device under test fails, high voltage may be present at a terminal to which Series 2600A instruments are connected. This could damage a Series 2600A instrument. To prevent damage to the Series 2600A instrument, use a Model 2657A-PM-200 Protection Module. Failure to use a protection module could result in equipment damage.

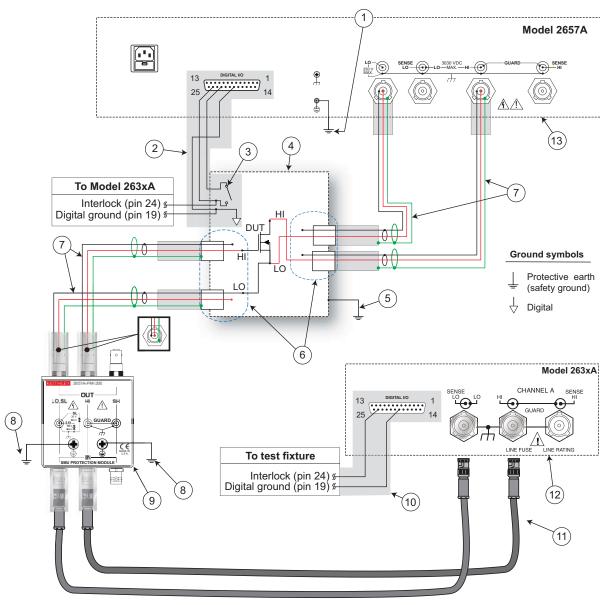


Figure 35: Schematic for measuring MOSFET characteristics application example

Item	Description	Qty	Notes
1	Model 2657A protective earth (safety ground)	1	Additional connections for redundant protective earth may be required. Keithley Instrument's Model CA-568 is a protective earth (safety ground) cable assembly.
2	Model 2657A interlock connection	1	Model 2657A digital I/O; pin 24 (INT) and pin 22 (5 VDC) connected to the test fixture lid switch. Pin 24 and pin 19 are connected to the interlock and digital ground on the Model 263xA. Keithley Instrument's Model 7709-308 is a 25-pin interlock male connector that can be used for custom connections. Interlock switch is shown in the disengaged (lid open) position.
3	Test fixture interlock switch connection	1	
4	Interlocked metal safety enclosure	1	A safety enclosure with an interlock that has a normally-open (NO) switch.
5	Test fixture protective earth (safety ground)	1	Redundant grounds may be required for specific test setups.
6	Model HV-CA-571-3 High-Voltage Triaxial Panel-Mount Cable to Unterminated Cable Assembly	4	See <u>Using high-voltage triaxial connectors</u> (on page 2-7).
7	Model HV-CA-554 HV Triaxial Cable	4	
8	Protective earth (safety ground) for the Model 2657A-PM-200 Protection Module	2	The Model 2657A-PM-200 must be connected to protective earth using the supplied green-yellow ground cables (Model CA-568).
9	Model 2657A-PM-200 Protection Module	1	
10	Model 2611A, 2612A, 2635A or 2636A interlock connection	1	Pin 24 (INT) and pin 19 (5 V DC) are connected to the test fixture lid switch.
11	Model 7078-TRX triaxial cables	2	
12	Series 2600A System SourceMeter Instrument (Model 2611A, Model 2612A, Model 2635A, or Model 2636A)	1	If a Model 2611A or 2612A is used, a Model 2600-TRIAX adapter is also required
13	Model 2657A	1	

If you are using a Model 8010 High Power Test Fixture, see the Interconnect Reference Guide drawing "Three-terminal DUT with a Model 2657A. Also see the Model 8010 User's Manual for information on how to connect the instrument to the fixture.

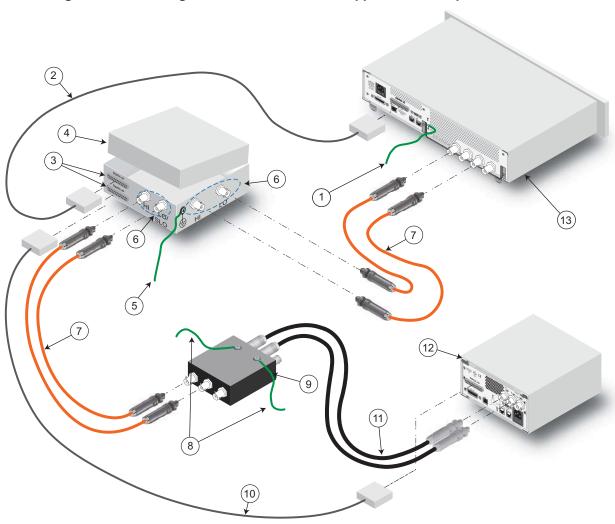


Figure 36: Measuring MOSFET characteristics application example connections

BVdss measurement

NOTE

The example code is designed to be run from Test Script Builder or TSB Embedded. It can also be run from other programming environments, such as Microsoft[®] Visual Studio[®] or National Instruments LabVIEWTM. However, you may need to make changes to the example code to use other programming environments.

This example performs the BV_{dss} measurement. The Model 2657A forces a current from the drain to source terminals and measures the resulting V_{ds} . This example uses a TSP script to perform the measurement. The script includes two separate functions for configuring the System SourceMeter Instrument and returning the raw current and voltage readings from the reading buffer.

The script is written using Test Script Processor (TSP) functions rather than as a single block of inline code. TSP functions are similar to functions in other programming languages, such as Microsoft® Visual C® or Visual Basic®. They must be called before the code in them is executed. Because of this, running the script alone will not execute the test. To execute the test, you need to run the script to load the functions into test script memory. You then call the functions.

Refer to the documentation for Test Script Builder or <u>TSB Embedded</u> (on page 4-4) for directions on how to run scripts and enter commands using the instrument console.

Example code

```
Title: FET Drain-Source Breakdown Voltage
  Description: This script measures the drain-source
  breakdown voltage (BVdss) of a FET.
--]]
--[[
  BVdss(gateV, drainI, measDelay, igLimit, vdLimit, numNPLC)
  Description: This function uses the Model 2657A to force a current
  from drain to source. The SMU also measures the resulting voltage (Vds)
  with the FET channel turned off. A second System SourceMeter Instrument
  applies the gate to source voltage (Vgs) to ensure that the gate is
  turned off.
  Parameters:
     gateV: Applied gate voltage (Vgs).
     drainI: Test current applied by the Model 2657A from
      drain to source (Id).
     measDelay: Measurement delay before making the drain voltage
      measurement (Vgs).
     igLimit: Current limit (compliance) for the SMU connected to the
      FET gate terminal.
     vdLimit: Voltage limit (compliance) for the SMU connected to the
      FET drain terminal.
     numNPLC: Integration time for the drain voltage measurement
       (in number of power line cycles).
  Example usage:
  BVdss(0, 0.001, 0.01, 0.01, 2000, 1)
--11
function BVdss(gateV, drainI, measDelay, igLimit, vdLimit, numNPLC)
   --Initialize SMU.
  reset()
  errorqueue.clear()
  status.reset()
  tsplink.reset()
  --Configure source function.
  node[2].smua.source.func = node[2].smua.OUTPUT DCVOLTS
  node[2].smua.source.levelv = gateV
  node[2].smua.source.limiti = igLimit
  smua.source.func = smua.OUTPUT DCAMPS
  smua.source.rangei = drainI
  smua.source.leveli = drainI
  smua.source.limitv = vdLimit
```

```
--Configure measurement parameters.

smua.measure.rangev = vdLimit

smua.measure.nplc = numNPLC

smua.measure.delay = measDelay

--Run the test.

node[2].smua.source.output = 1

smua.source.output = 1

I,V = smua.measure.iv()

smua.source.output = 0

node[2].smua.source.output = 0

print("Test current:", I)

print("Measured voltage:", V)

end
```

Example usage

The function in this script allows updates to the test parameters without rewriting or re-running the script. To run the test, call the BVdss () function, passing in the appropriate values for test parameters.

BVdss() parameters			
Parameter	Units	Description	
gateV	volts	Gate voltage to apply with Series 2600A System SourceMeter Instrument	
drainI	amps	Drain current forced by Model 2657A	
measDelay	seconds	Measurement delay after applying drain current and before measuring BV _{dss}	
igLimit	amps	Current limit for the Series 2600A SourceMeter Instrument connected to the MOSFET gate terminal	
vdLimit	volts	Voltage limit (compliance) for the Model 2657A connected to the MOSFET drain terminal; should be greater than or equal to the expected ${\sf BV}_{\sf dss}$ value	
numNPLC	not applicable	Integration time, specified as the number of power line cycles	

An example of how to call this function is shown here:

```
BVdss(0, 0.001, 0.01, 0.01, 2000, 1)
```

This call applies 0 V to the FET gate terminal and programs the Model 2657A to force 1 mA into the drain terminal. After 10 ms, the drain voltage is measured (up to 2000 V max). The measurement is made at 1 PLC. The actual drain current is also measured. The measurement results are automatically printed at the completion of the test. An example of the measurements results is:

```
Test current: 9.99856e-04
Measured voltage: 1.76940e+03
```

Idss measurement

This example:

- Performs the I_{dss} measurement, where the drain-to-source voltage (V_{ds}) is swept and leakage current measurements are made while the FET is in the off-state.
- Monitors the current measurement to see if the current limit has been reached. When the current limit has been reached, the voltage sweep is aborted.

With this method, a second System SourceMeter is used to apply a voltage from gate to source (V_{gs}). This example uses a TSP script to perform the measurement. The script includes two separate functions for configuring the System SourceMeter Instruments and returning the raw current and voltage readings from the reading buffer.

Example code

```
--[[
  Title: FET Drain-to-Source Leakage Current Measurement Sweep
  Description: This script measures the drain current while the
  drain voltage is sweeping linearly and under a 0 V gate bias.
--11
--[[
  Idss (gateV, startV, stopV, numSteps, measDelay, measRange, iLimit, numNPLC)
  Description: This function uses the Model 2657A to sweep the voltage
  across the drain up to the drain-source breakdown voltage and measure
  the drain current. A second SourceMeter instrument is used to bias the
  gate. For enhancement-mode power MOSFETs, a typical gate bias is 0 V.
  Parameters:
     gateV: Applied gate voltage bias (Vgs).
     startV: Starting drain voltage (Vds).
     stopV: Final drain voltage (Vds).
     numSteps: Number of points in the drain voltage sweep.
     measDelay: Measurement delay.
     measRange: Current measurement range for the drain current measurements.
     iLimit: Current limit (compliance) for the drain current.
     numNPLC: Integration time in the number of power line cycles.
  Example Usage:
  Idss(0, 10, 1760, 500, 0.05, 100e-9, 500e-6, 1)
--11
```

```
function Idss(gateV, startV, stopV, numSteps, measDelay, measRange, iLimit,
   numNPLC)
  --Initialize SMU.
  reset()
  errorqueue.clear()
  status.reset()
  --Configure reading buffers.
  smua.nvbuffer1.clear()
  smua.nvbuffer1.appendmode = 1
  smua.nvbuffer1.collecttimestamps = 1
  smua.nvbuffer2.clear()
  smua.nvbuffer2.appendmode = 1
  smua.nvbuffer2.collecttimestamps = 1
  -- Configure source parameters for the gate SMU.
  node[2].smua.source.func = node[2].smua.OUTPUT DCVOLTS
  node[2].smua.source.levelv = gateV
  node[2].smua.source.limiti = 0.001
  --Configure source parameters for the drain SMU.
  smua.source.func = smua.OUTPUT DCVOLTS
  smua.source.levelv = 0
  smua.source.limiti = iLimit
  if math.abs(startV) > math.abs(stopV) then
     smua.source.rangev = startV
  else
     smua.source.rangev = stopV
  --Configure measurement parameters for the drain SMU.
  smua.measure.rangei = measRange
  smua.measure.nplc = numNPLC
  smua.measure.delay = measDelay
  step = (stopV - startV) / (numSteps - 1)
  voltage = startV
  smua.source.levelv = voltage
```

```
--Run the test.
  node[2].smua.source.output = 1
  smua.source.output = 1
  delay(1)
  for i = 1, numSteps do
      smua.measure.iv(smua.nvbuffer1, smua.nvbuffer2);
      --Remove the following 4 lines if you do not want to monitor
     --for compliance
     testCmpl = smua.source.compliance
     if testCmpl == true then
        break
     end
     smua.source.levelv = voltage + step
     voltage = voltage + step
  --Turn off the SMUs to complete the test.
  smua.source.levelv = 0
  node[2].smua.source.levelv = 0
  node[2].smua.source.output = 0
  smua.source.output = 0
  printData()
end
function printData()
  if smua.nvbuffer1.n == 0 then
     print("No reading in buffer")
  else
     print("Timestamps\tVoltage\tCurrent")
     for i = 1, smua.nvbuffer1.n do
        print(string.format("%g\t%g", smua.nvbuffer1.timestamps[i],
          smua.nvbuffer2.readings[i], smua.nvbuffer1.readings[i]))
      end
  end
end
```

Example usage

The functions in this script allow updates to the test parameters without rewriting or re-running the script. To run the test, call the Idss() function, passing in the appropriate values for test parameters.

ldss() parameters			
Parameter	Units	Description	
gateV	volts	Gate voltage to apply with Series 2600A System SourceMeter Instrument	
startV	volts	Start voltage for the drain voltage sweep	
stopV	volts	Final voltage for the drain voltage sweep	
numSteps	not applicable	Number of voltage steps to perform in the voltage sweep	
measDelay	seconds	Measurement delay after applying drain voltage and before measuring drain leakage current	
measRange	amps	Fixed current measurement range used to measure drain leakage current	
iLimit	amps	Current limit (compliance) for the Model 2657A connected to the MOSFET drain terminal	
numNPLC	not applicable	Integration time, specified as the number of power line cycles	

An example of how to call this function is shown here:

```
Idss(0, 10, 1760, 500, 0.05, 100e-9, 500e-6, 1)
```

This call applies 0 V to the MOSFET gate terminal and programs the Model 2657A to generate a 500 point voltage sweep from 10 V to 1760 V at the drain terminal. After each voltage step, a 50 ms delay occurs before the current is measured. The measurement is made at 1 PLC. The measurements are stored in the instrument's reading buffers and are output from the communication interface immediately after the test is run.

Example output data is shown in the following graphic.

Figure 37: Example output data

Measurement of Idss vs. Drain Voltage

